

SBT-70 LEDs

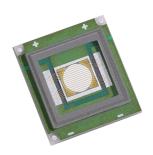


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Features:

- Extremely high optical output from a 7 mm² circular emitter:
 - Over 2,000 green lumens at 10.5A
 - Over 200 blue lumens at 10.5A and 445nm
 - Refer to SBT-90-R for companion red product
- Round emitting aperture provides most efficient match to circular optical systems and narrow beam projectors
- Unencapsulated die with low profile protective window optimizes optical coupling in etendue-limited applications
- High thermal conductivity package junction to case thermal resistance of only 0.64°C/W
- Variable drive current up to 10.5 A continuous wave. Up to 2A/mm² in pulsed conditions
- Environmentally friendly: RoHS compliant

Applications

- Architectural and Entertainment Lighting
- Fiber-coupled Illumination
- Medical Lighting

- Machine Vision
- Microscopy
- Spot Lighting





Technology Overview

Luminus LEDs™ benefit from a suite of innovations in the fields of LED die technology, packaging and thermal management. These breakthroughs allow illumination engineers and designers to achieve solutions that are high brightness and high efficiency.

Luminus Technology

Luminus' technology enables large area LED chips with uniform brightness over the entire LED chip surface. The optical power and brightness produced by these large monolithic chips enable solutions which replace arc and halogen lamps where arrays of traditional high power LEDs cannot.

Packaging Technology

Thermal management is critical in high power LED applications. With a thermal resistance from junction to case of 0.64° C/W, Luminus SBT-70 LEDs have the lowest thermal resistance of any LED on the market. This allows the LED to be driven at higher current densities while maintaining a low junction temperature, thereby resulting in brighter solutions and longer lifetimes.

Reliability

Designed from the ground up, Luminus LEDs are one of the most reliable light sources in the world today. Luminus LEDs have passed a rigorous suite of environmental and mechanical stress tests, including mechanical shock, vibration, temperature cycling and humidity, and have been fully qualified for use in extreme high power and high current applications. With very low failure rates and median lifetimes that typically exceed 60,000 hours, Luminus LEDs are ready for even the most demanding applications.

Environmental Benefits

Luminus LEDs help reduce power consumption and the amount of hazardous waste entering the environment. All LED products manufactured by Luminus are RoHS compliant and free of hazardous materials, including lead and mercury.

Understanding Big Chip LED Test Specifications

Every Luminus LED is fully tested to ensure that it meets the high quality standards expected from Luminus' products.

Testing Temperature

Luminus surface mount LEDs are typically tested with a 20 ms input pulse and a junction temperature of 25°C. Expected flux values in real world operation can be extrapolated based on the information contained within this product data sheet.



SBT-70 G, B Binning Structure (T_j= 25°C)

SBT-70 monochromatic LEDs are tested for luminous flux and dominant wavelength at a 10.5 A (1.5 A/mm²) drive current and placed into one of the following flux and wavelength bins. The binning structure is universally applied across each monochromatic color.

Flux Bins (measured at 10.5A drive current)

| Color | Luminous Flux Bin (FF) | Minimum Flux | Maximum Flux |
|-------|------------------------|--------------|--------------|
| | CK | 1500 | 2000 |
| Green | CM | 2000 | 2300 |
| | CN | 2300 | 2600 |
| | DF | 120 | 160 |
| Blue | DG | 160 | 200 |
| | DH | 200 | 250 |

^{*}Note: Luminus maintains a +/- 6% tolerance on flux measurements.

Wavelength Bins Measured at 10.5 A drive current

| Color | Wavelength Bin (WW) Minimum Wavelength Maximum Wave | | Maximum Wavelength |
|-------|---|-----|--------------------|
| | G4 | 520 | 525 |
| Cyana | G5 | 525 | 530 |
| Green | G6 | 530 | 535 |
| | G7 | 535 | 540 |
| | B1 | 435 | 440 |
| Di | B2 | 440 | 445 |
| Blue | B3 | 445 | 450 |
| | B4 | 450 | 455 |



Product Shipping & Labeling Information

All SBT-70 products are packaged and labeled with their respective bin as outlined in the tables on page 3. When shipped, each package will only contain one bin. The part number designation is as follows:

| SBT-70-G, B | | | | | | |
|---------------------------|---------------|---------------------|-----------------------|-----------------------------|-------------------------------------|--|
| SBT - | — 70 — | – N – | — F75 — | – FF – | – ww | |
| Product Family | Chip Area | Color | Package Configuration | Flux Bin | Wavelength Bin | |
| Surface Mount (window) | 7.0 mm² | G: Green B: Blue | Internal Code | See page 3 for flux bins | See page 3 for wave- length bins | |

Example:

The part number SBT-70-B-F75-DH-B2 refers to a BLUE, SBT-70 surface mount, with a flux range of 200 - 250 lumens and a wavelength range of 440 nm to 445 nm.

Note: Some flux and wavelength bins may have limited availability. Application specific bin kits, consisting of multiple bins, may be available.

Table of Products

| Products | Ordering Part Number | Description | |
|----------|----------------------|--|--|
| SBT-70-G | SBT-70-G-F75-xx123 | SBT-70 surface mount device consisting of a 7.0 mm ² | |
| SBT-70-B | SBT-70-B-F75-xx123 | LED on ceramic substrate | |
| SBR-70-G | SBR-70-G-R75-xx123 | SBR-70 evaluation module consisting of a SBT-70 surface mount device | |
| SBR-70-B | SBR-70-B-R75-xx123 | mounted on an aluminum star board | |

Please refer to page 5 for orderable bin kits.



SBT-70 and SBR-70 Bin Kit Order Codes

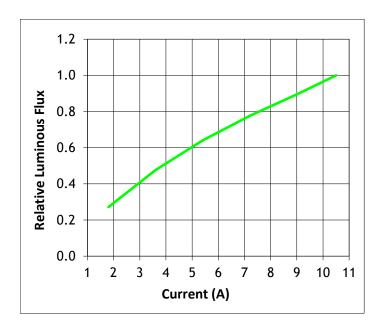
| | Luminous F | | | | |
|---------|----------------------|-----------|-----------------|------------|--|
| Color | Bin Kit Flux Code | Min. Flux | Wavelength Bins | Kit Number | |
| | | | G4, G5, G6, G7 | JK200 | |
| | JK | 1500 | G4, G5 | JK201 | |
| Cunn | | | G6, G7 | JK202 | |
| Green | | 2000 | G4, G5, G6, G7 | JM200 | |
| | JM | | G4, G5 | JM201 | |
| | | | G6, G7 | JM202 | |
| | 145 | 120 | B1,B2,B3,B4 | KF300 | |
| Dlue | KF | 120 | B2,B3 | KF301 | |
| Blue KG | VC | 160 | B1,B2,B3,B4 | KG300 | |
| | 160 | B2,B3 | KG301 | | |



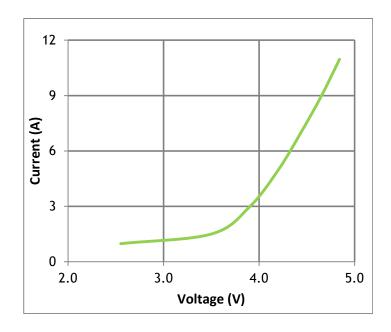
SBT-70 G, B, Optical & Electrical Characteristics

| Green | | | | | | |
|---|---------------------------------|---------------------|-------|--|--|--|
| Drive Condition ¹ | | 10.5 A | | | | |
| Parameter | Symbol | Values ³ | Unit | | | |
| Current Density | j | 1.5 | A/mm² | | | |
| | $V_{_{\mathrm{F}\mathrm{min}}}$ | 3.9 | V | | | |
| Forward Voltage | V _F | 4.5 | V | | | |
| Γ | V_{Fmax} | 5.3 | V | | | |
| Luminous Flux⁴ | Φ _{V typ} | 2100 | lm | | | |
| Dominant Wavelength ⁶ | λ_{d} | 530 | nm | | | |
| FWHM | Δλ _{1/2} | 32 | nm | | | |
| Chromaticity Coordinates ^{5,6} | Х | 0.182 | - | | | |
| | у | 0.732 | - | | | |

Relative Luminous Flux vs. Forward Current²



Forward Current vs. Forward Voltage



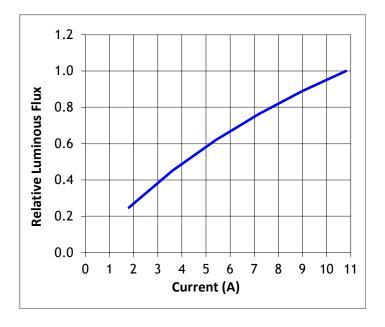
For notes see page 8.



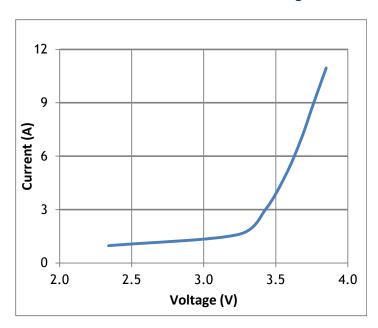
SBT-70 G, B, Optical & Electrical Characteristics

| Blue | | | | | |
|---|--------------------------|---------------------|-------|--|--|
| Drive Condition ¹ | | 10.5 A | | | |
| Parameter | Symbol | Values ³ | Unit | | |
| Current Density | j | 1.5 | A/mm² | | |
| | $V_{_{Fmin}}$ | 3.2 | V | | |
| Forward Voltage | $V_{_{\rm F}}$ | 3.8 | V | | |
| Ι Γ | V_{Fmax} | 4.2 | V | | |
| Luminous Flux ⁴ | $\Phi_{ m V typ}$ | 200 | lm | | |
| Dominant Wavelength ⁶ | λ_{d} | 445 | nm | | |
| Radiometric Flux | $\Phi_{_{p}typ}$ | 9.5 | W | | |
| FWHM | $\Delta\lambda_{_{1/2}}$ | 19 | nm | | |
| Chromaticity Coordinates ^{5,6} | Х | 0.158 | - | | |
| Ciliomaticity Coordinates. | у | 0.018 | - | | |

Relative Luminous Flux vs. Forward Current²



Forward Current vs. Forward Voltage



For notes see page 8.





SBT-70, G, B, Optical & Electrical Characteristics Notes

- Note 1: Listed drive conditions are typical for common applications. SBT-70 G,B devices can be driven at currents ranging from 1 A to 10.5 A and at duty cycles ranging from 1% to 100%. Drive current and duty cycle should be adjusted as necessary to maintain the junction temperature desired to meet application lifetime requirements.
- Note 2: All ratings are based on a junction test temperature $T_j = 25^{\circ}$ C. See Thermal Resistance section for T_j definition.
- Note 3: Unless otherwise noted, values listed are typical. Devices are production tested and specified at 10.5A. Other values are for reference only.
- Note 4: Total flux from emitting area at listed dominant wavelength. Reported performance is included to show trends for a selected power level. For specific minimum and maximum values, use bin tables. For product roadmap and future performance of devices, contact Luminus.
- Note 5: In CIE 1931 chromaticity diagram coordinates, normalized to X+Y+Z=1.
- Note 6: For reference only.

SBT-70-G, B

Common Characteristics

| | Symbol | Green | Blue | Unit |
|---|--------|-------|------|--------|
| Emitting Area | | 7.0 | 7.0 | mm² |
| Emitting Area (Diameter) | | 3 | 3 | mm |
| Thermal Coefficient of Photometric Flux | | -0.2 | -0.2 | %/ ℃ |
| Thermal Coefficient of Radiometric Flux | | -0.2 | -0.2 | %/ ℃ |
| Thermal Coefficient of Junction Voltage | | -4.6 | -3.5 | mV/ °C |

Absolute Maximum Ratings

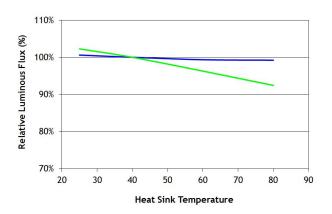
| | Symbol | Green | Blue | Unit |
|---|------------|----------|----------|------|
| Minimum Current | | 0.2 | 0.2 | Α |
| Maximum Current ⁷ | | 14 | 14 | Α |
| Maximum Junction Temperature ⁸ | T_{jmax} | 150 | 150 | ∘C |
| Storage Temperature Range | | -40/+100 | -40/+100 | °C |

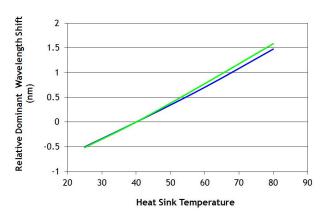
Note 7: Luminus LEDs are designed for operation to an absolute maximum current as specified above. Product lifetime data is specified at recommended forward drive currents. Sustained operation at or beyond absolute maximum currents will result in a reduction of device lifetime compared to recommended forward drive currents. Actual device lifetimes will also depend on junction temperature. Refer to the lifetime derating curves for further information. In pulsed operation, rise time from 10-90% of forward current should be larger than 0.5 microseconds.

Note 8: Lifetime dependent on LED junction temperature. Input power and thermal system must be properly managed to ensure lifetime. See charts on pg 9 for further information.

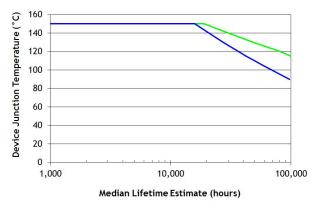


SBT-70-G, B Output vs. Temp., Lifetime and Spectrum

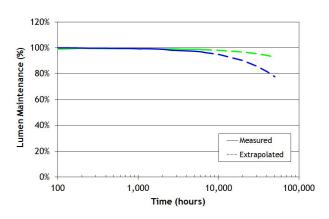




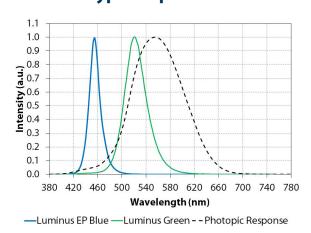
Median Lifetime Estimate vs. Tj¹



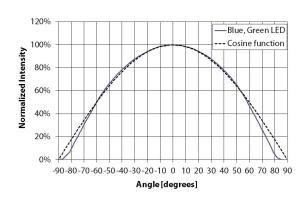
Lumen Maintenance²



Typical Spectrum³



Angular Distribution

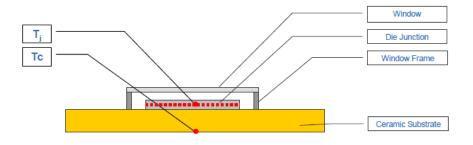


- Note 1. Median lifetime estimate as a function of junction temperature at 1.5A/mm² in continuous operation. Lifetime defined as time to 70% of initial intensity. Based on preliminary lifetime test data. Data can be used to model failure rate over typical product lifetime.
- Note 2. Lumen maintenance vs. time at 1.5A/mm 2 in continuous operation, junction temperature equal to 25 $^\circ$ C.
- Note 3. Typical spectrum at current density of 1.5 A/mm² in continuous operation.



Thermal Resistance

Thermal Resistance Model



Typical Thermal Resistance:

| R _{j-c} ¹ | 0.64 °C/W |
|--------------------------------|-----------|
| R _{j-b} ¹ | 2.02 °C/W |
| R _{j-hs} ² | 2.15 °C/W |

Note 1: Thermal resistance values are based on FEA model results correlated to measured $R_{\theta j \text{-} hs}$ data.

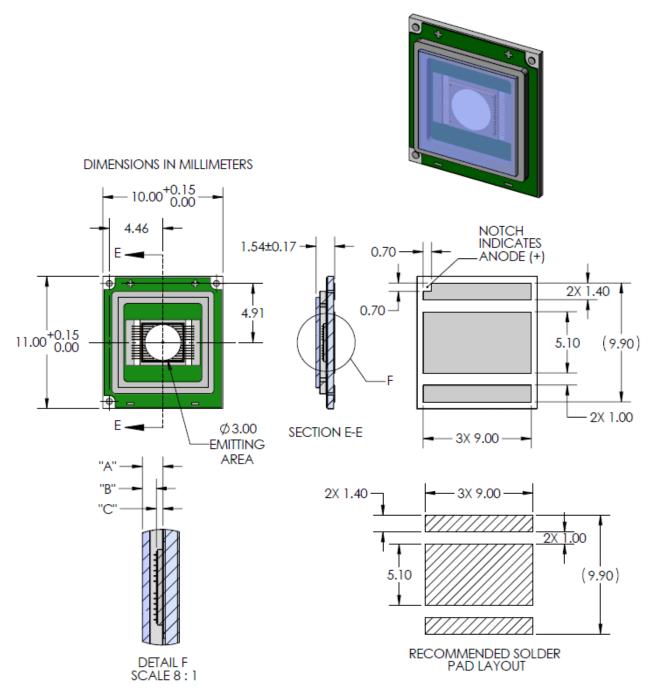
Note 2: Thermal resistance is measured using a SAC305 solder, a Bergquist Al-clad MCPCB, and eGraf 1205 thermal interface material.

Thermal resistance values are preliminary based on modeled results.

Note:



Mechanical Dimensions – SBT-70 Emitter



| DIMENSION NAME | DESCRIPTION | NOMINAL DIMENSION | TOLERANCE |
|-------------------|--|----------------------|-----------|
| "A" | TOP OF CERAMIC SUBSTRATE TO TOP OF GLASS | .86 | ±0.10 |
| "B" | TOP OF EMITTING AREA TO TOP OF GLASS | .58 | ±0.14 |
| "C" | TOP OF CERAMIC SUBSTRATE TO TOP OF EMITTING AREA | .28 | ±0.03 |

DWG-002087



Mechanical Dimensions – SBT-70 Star Board

DIMENSIONS IN MILLIMETERS 3.440.22 TOP OF WINDOW TO BACK OF CORESOARD 4X.7.1 4X.4.1 3.40.22 TOP OF WINDOW TO BACK OF CORESOARD 4X.4.1 10.00*0.15 11.00*0.15 11.00*0.15 11.00*0.15 11.00*0.15 11.00*0.15 11.00*0.15

DWG-002153

Note 1: Tolerances per IPC-610, Class 2. All dimensions in millimeters

Note 2: For detail drawing of SBT-70, please see DWG-002087

Note 3: Recommended mounting screw: M3 or #4

Note 4: All anode pads and all cathode pads on board are interconnected.



History of Changes

| Rev | Date | Description of Change |
|-----|------------|--|
| 08 | 07/20/2015 | Added Angular Distribution Pattern on Page 9 |
| 09 | 04/10/2016 | Updated Vf min for SBT-70-G from 4.5V to 3.9V and typical Vf from 4.9V to 4.5V Corrected maximum current value to 14A (2A/mm²) on page 8 |

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